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Kind regards,

Team Nexperia

# PDTD123Y series

NPN 500 mA, 50 V resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

Rev. 02 — 16 November 2009

Product data sheet

### 1. Product profile

### 1.1 General description

500 mA NPN Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package			PNP complement
	NXP	JEITA	JEDEC	
PDTD123YK	SOT346	SC-59A	TO-236	PDTB123YK
PDTD123YS[1]	SOT54	SC-43A	TO-92	PDTB123YS
PDTD123YT	SOT23	-	TO-236AB	PDTB123YT

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2).

### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 500 mA output current capability
- Reduces component count
- Reduces pick and place costs
- ±10 % resistor ratio tolerance

### 1.3 Applications

- Digital application in automotive and industrial segment
- Controlling IC inputs

- Cost saving alternative for BC817 series in digital applications
- Switching loads

### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>O</sub>	output current (DC)		-	-	500	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		4.1	4.55	5	



## 2. Pinning information

Table 3. **Pinning** Simplified outline Pin **Description Symbol** SOT54 1 input (base) 2 output (collector) 3 GND (emitter) 001aab347 SOT54A 1 input (base) 2 output (collector) 3 GND (emitter) 001aab348 006aaa145 **SOT54** variant 1 input (base) 2 output (collector) 3 GND (emitter) 001aab447 006aaa145 **SOT23, SOT346** 1 input (base) 3 2 GND (emitter) 3 output (collector) 2

2 of 10

sym007

006aaa144

## 3. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
PDTD123YK	SC-59A	plastic surface mounted package; 3 leads	SOT346			
PDTD123YS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
PDTD123YT	-	plastic surface mounted package; 3 leads	SOT23			

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

# 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PDTD123YK	E7
PDTD123YS	D123YS
PDTD123YT	*7X

<sup>[1] \* = -:</sup> made in Hong Kong

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
VI	input voltage				
	positive		-	+12	V
	negative		-	<b>-</b> 5	V
I <sub>O</sub>	output current (DC)		-	500	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$	[1]		
	SOT346		-	250	mW
	SOT54		-	500	mW
	SOT23		-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

PDTD123Y\_SER\_2

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]			
	SOT346		-	-	500	K/W
	SOT54		-	-	250	K/W
	SOT23		-	-	500	K/W

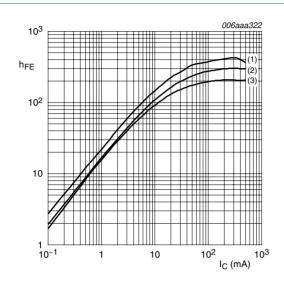
<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{CBO}$	collector-base cut-off	$V_{CB} = 40 \text{ V}; I_{E} = 0 \text{ A}$	-	-	100	nA
	current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 50 \text{ V}; I_B = 0 \text{ A}$	-	-	0.5	μА
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$	-	-	0.65	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}$	70	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$	-	-	0.3	V
$V_{I(off)}$	off-state input voltage	$V_{CE}$ = 5 V; $I_{C}$ = 100 $\mu A$	0.4	0.6	1	V
$V_{I(on)}$	on-state input voltage	$V_{CE}$ = 0.3 V; $I_{C}$ = 20 mA	0.5	1	1.4	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		4.1	4.55	5	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	7	-	pF



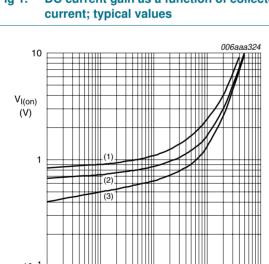
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 1. DC current gain as a function of collector current; typical values



10

10<sup>2</sup>

I<sub>C</sub> (mA)

10<sup>3</sup>

$$V_{CE} = 0.3 \text{ V}$$

1

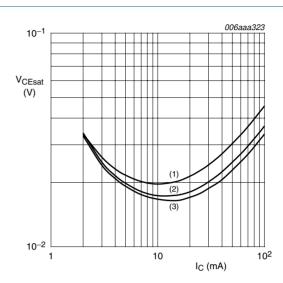
(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

10<sup>-1</sup>

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

On-state input voltage as a function of Fig 3. collector current; typical values



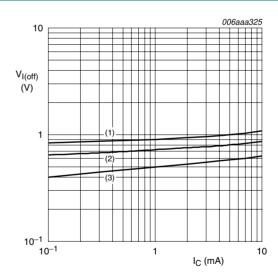
$$I_C/I_B = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



$$V_{CE} = 5 \text{ V}$$

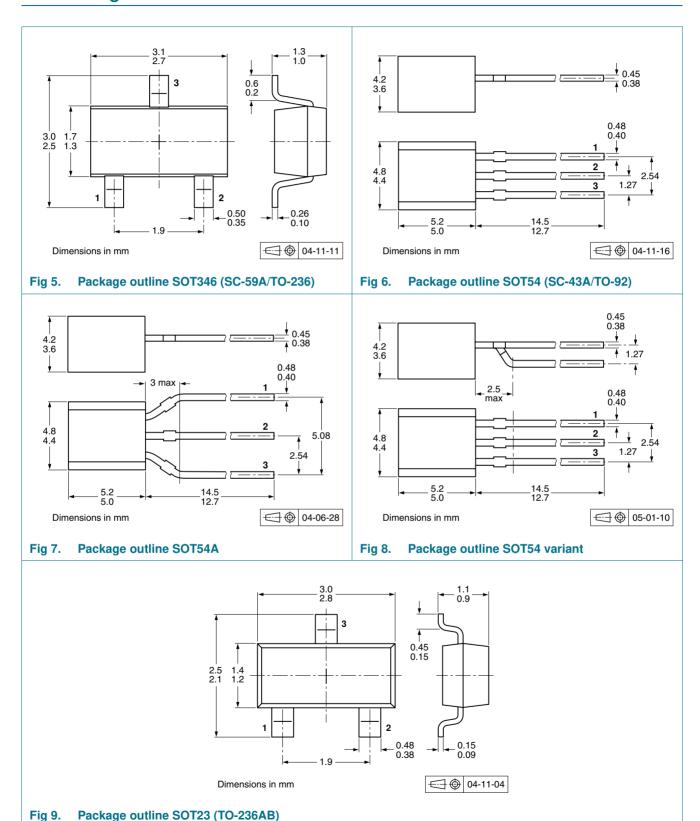
(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Off-state input voltage as a function of Fig 4. collector current; typical values

### 8. Package outline



# 9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTD123YK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTD123YS	SOT54	bulk, straight leads	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-116
		tape ammopack, wide pitch	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-112	-
PDTD123YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.



# 10. Revision history

### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTD123Y_SER_2	20091116	Product data sheet	-	PDTD123Y_SER_1			
Modifications:	including nev content.	data sheet was changed to reflect the new company name NXP Semiconductors, uding new legal definitions and disclaimers. No changes were made to the technical tent.  e 3 "Pinning": updated					
PDTD123Y_SER_1	20050412	Product data sheet	-	-			

### 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# PDTD123Y series

### NPN 500 mA resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$

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